

MOSFETs   Silicon N-Channel MOS (DTMOSVI)

TK063N60Z1

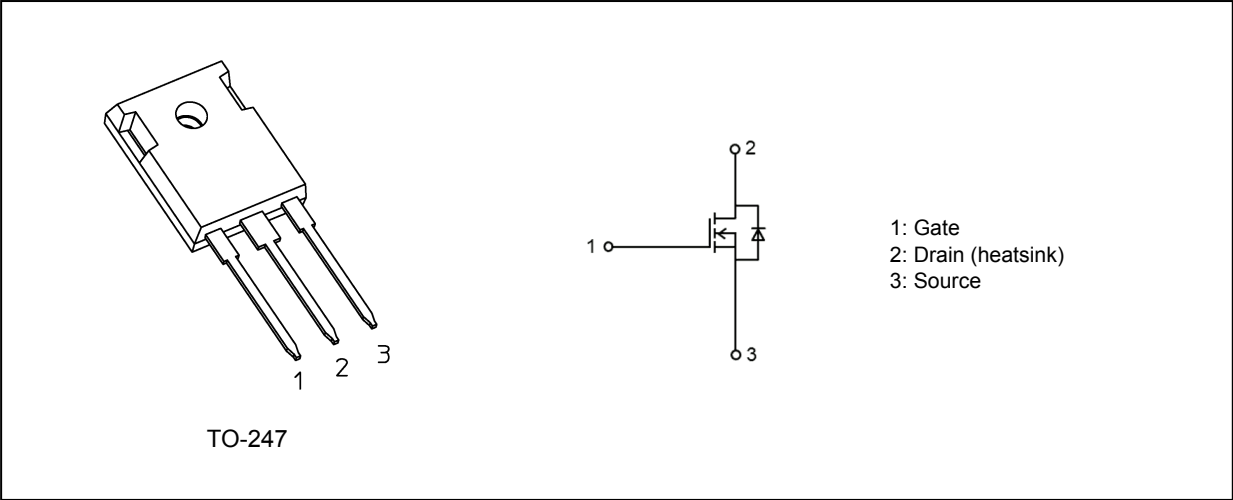
1. Applications

- Switching Power Supplies

2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 0.053 \Omega$  (typ.)
- (2) High-speed switching properties with lower capacitance.
- (3) Enhancement mode:  $V_{th} = 3$  to  $4 \text{ V}$  ( $V_{DS} = 10 \text{ V}$ ,  $I_D = 1.47 \text{ mA}$ )

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ( $T_a = 25 \text{ }^\circ\text{C}$  unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	600	V
Gate-source voltage	$V_{GSS}$	$\pm 30$	
Drain current (DC) (Note 1)	$I_D$	37	A
Drain current (pulsed) (Note 1)	$I_{DP}$	148	
Power dissipation ( $T_c = 25 \text{ }^\circ\text{C}$ )	$P_D$	242	W
Single-pulse avalanche energy (Note 2)	$E_{AS}$	609	mJ
Single-pulse avalanche current	$I_{AS}$	6.1	
Reverse drain current (DC) (Note 1)	$I_{DR}$	37	
Reverse drain current (pulsed) (Note 1)	$I_{DRP}$	148	
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to 150	
Mounting torque	TOR	0.8	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production  
2024-11

## 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	$R_{th(ch-c)}$	0.515	°C/W
Channel-to-ambient thermal resistance	$R_{th(ch-a)}$	50	

Note 1: Ensure that the channel temperature does not exceed 150 °C.

Note 2:  $V_{DD} = 90$  V,  $T_{ch} = 25$  °C (initial),  $L = 29$  mH,  $I_{AS} = 6.1$  A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

## 6. Electrical Characteristics

### 6.1. Static Characteristics ( $T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 30$ V, $V_{DS} = 0$ V	—	—	$\pm 1$	$\mu$ A
Drain cut-off current	$I_{DSS}$	$V_{DS} = 600$ V, $V_{GS} = 0$ V	—	—	2	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10$ mA, $V_{GS} = 0$ V	600	—	—	V
Gate threshold voltage	$V_{th}$	$V_{DS} = 10$ V, $I_D = 1.47$ mA	3	—	4	
Drain-source on-resistance	$R_{DS(ON)}$	$V_{GS} = 10$ V, $I_D = 12.8$ A	—	0.053	0.063	$\Omega$

### 6.2. Dynamic Characteristics ( $T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	$C_{iss}$	$V_{DS} = 300$ V, $V_{GS} = 0$ V, $f = 100$ kHz	—	3200	—	pF
Reverse transfer capacitance	$C_{rss}$		—	3	—	
Output capacitance	$C_{oss}$		—	77	—	
Effective output capacitance (Note 3) (energy related)	$C_{O(er)}$	$V_{DS} = 0$ to 400 V, $V_{GS} = 0$ V	—	128	—	
Effective output capacitance (Note 4) (time related)	$C_{O(tr)}$	$V_{DS} = 0$ to 400 V, $V_{GS} = 0$ V	—	910	—	
Gate resistance	$r_g$	$V_{DS} = OPEN$ , $f = 1$ MHz	—	2.5	—	$\Omega$
Switching time (rise time)	$t_r$	See Fig.6.2.1	—	50	—	ns
Switching time (turn-on time)	$t_{on}$		—	84	—	
Switching time (fall time)	$t_f$		—	5	—	
Switching time (turn-off time)	$t_{off}$		—	105	—	
MOSFET dv/dt ruggedness	dv/dt	$V_{DS} \leq V_{DSS}$ , $I_D \leq 18.5$ A	120	—	—	V/ns

Note 3:  $C_{O(er)}$  is a fixed capacitance that gives the same stored energy as  $C_{OSS}$  while  $V_{DS}$  is rising from 0 V to 400 V.

Note 4:  $C_{O(tr)}$  is a fixed capacitance that gives the same charging time as  $C_{OSS}$  while  $V_{DS}$  is rising from 0 V to 400 V.

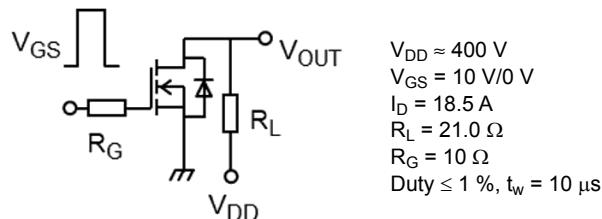


Fig. 6.2.1 Switching Time Test Circuit

## 6.3. Gate Charge Characteristics ( $T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} \approx 400\text{ V}$ , $V_{GS} = 10\text{ V}$ , $I_D = 37\text{ A}$	—	56	—	nC
Gate-source charge 1	$Q_{gs1}$		—	18	—	
Gate-drain charge	$Q_{gd}$		—	15	—	

## 6.4. Source-Drain Characteristics ( $T_a = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Diode forward voltage	$V_{DSF}$	$I_{DR} = 37\text{ A}$ , $V_{GS} = 0\text{ V}$	—	—	-1.7	V
Reverse recovery time	$t_{rr}$	$V_{DD} = 400\text{ V}$ , $I_{DR} = 18.5\text{ A}$ , $V_{GS} = 0\text{ V}$ $-dI_{DR}/dt = 100\text{ A}/\mu\text{s}$	—	350	—	ns
Reverse recovery charge	$Q_{rr}$		—	5.3	—	$\mu\text{C}$
Peak reverse recovery current	$I_{rr}$		—	30	—	A
Diode dv/dt ruggedness	dv/dt	$V_{DD} \leq 400\text{ V}$ , $I_{DR} \leq 18.5\text{ A}$ , $V_{GS} = 0\text{ V}$	40	—	—	V/ns

## 7. Marking (Note)

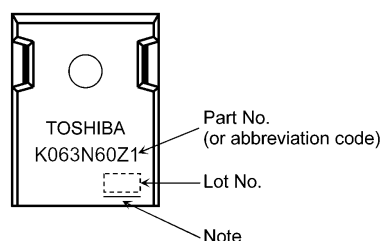


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

Not underlined:  $[[Pb]]/INCLUDES > MCV$

Underlined:  $[[G]]/RoHS\ COMPATIBLE$  or  $[[G]]/RoHS\ [[Pb]]$

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

8. Characteristics Curves (Note)

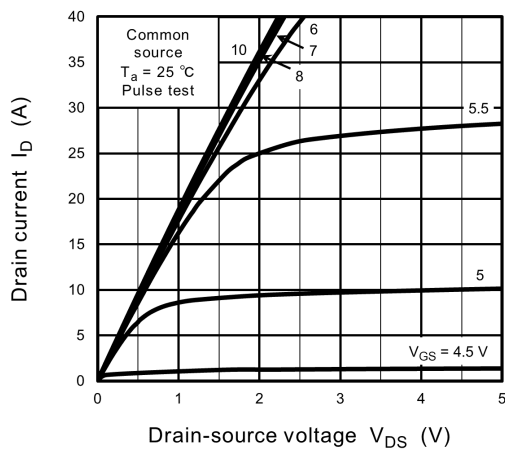


Fig. 8.1  $I_D - V_{DS}$

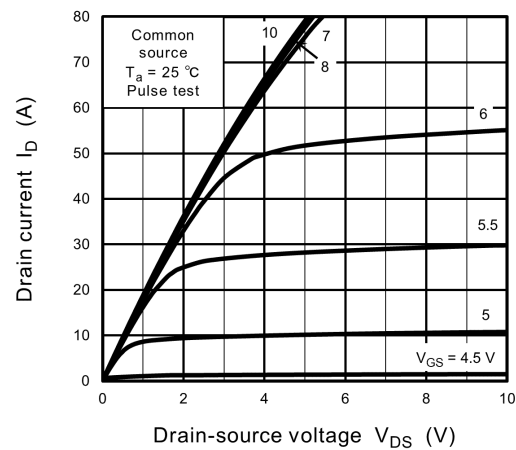


Fig. 8.2  $I_D - V_{DS}$

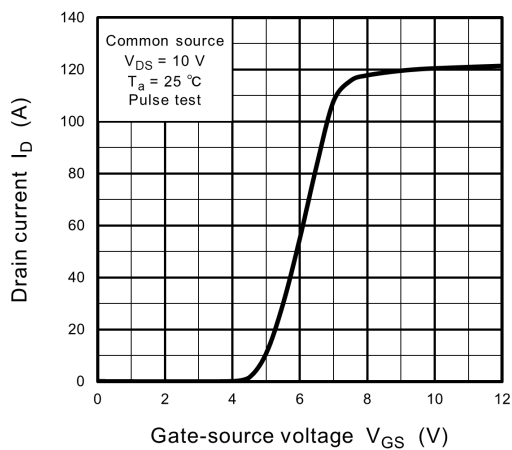


Fig. 8.3  $I_D - V_{GS}$

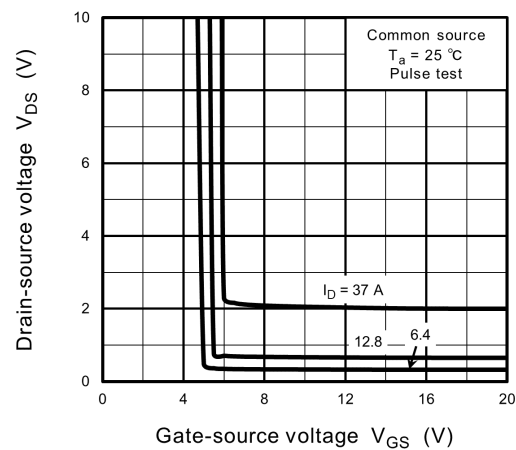


Fig. 8.4  $V_{DS} - V_{GS}$

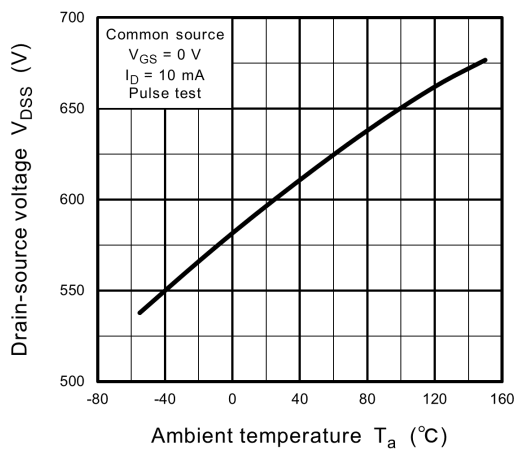


Fig. 8.5  $V_{DSS} - T_a$

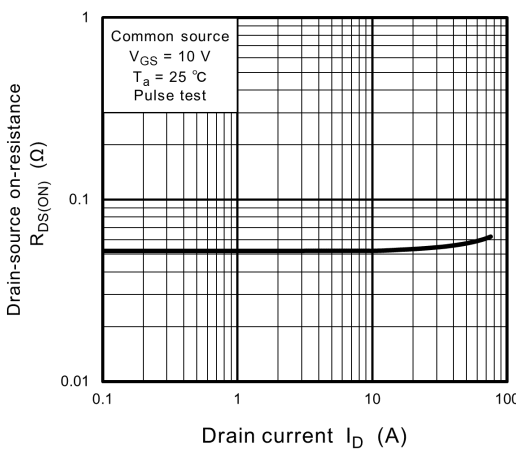


Fig. 8.6  $R_{DS(ON)} - I_D$

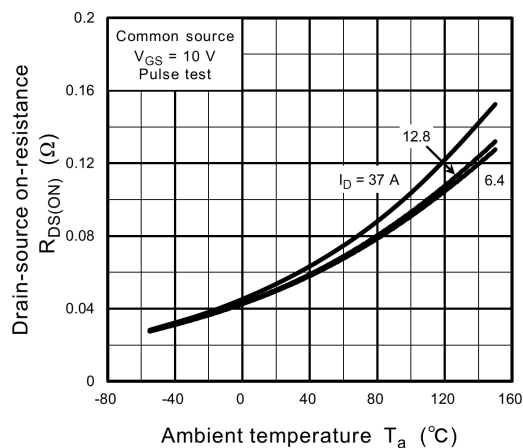


Fig. 8.7  $R_{DS(ON)} - T_a$

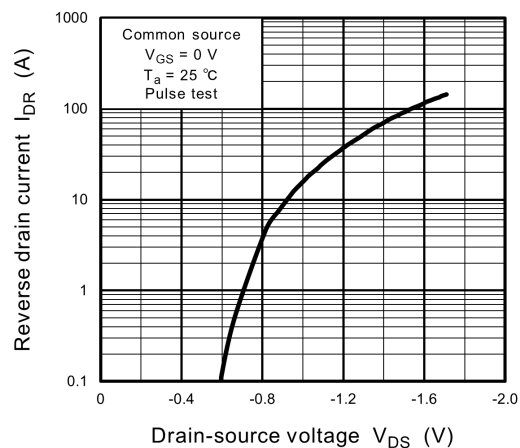


Fig. 8.8  $I_{DR} - V_{DS}$

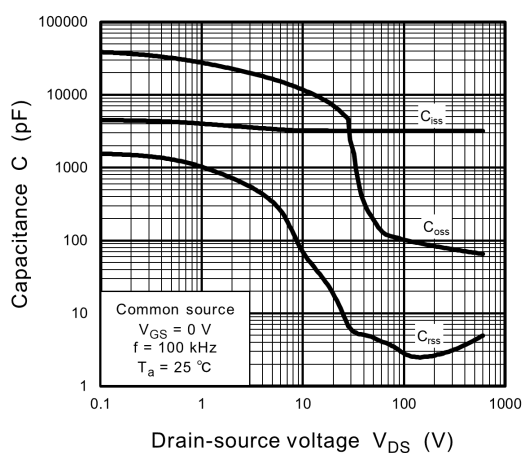


Fig. 8.9  $C - V_{DS}$

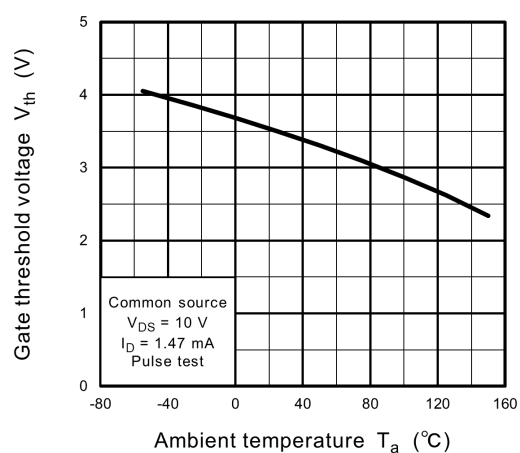


Fig. 8.10  $V_{th} - T_a$

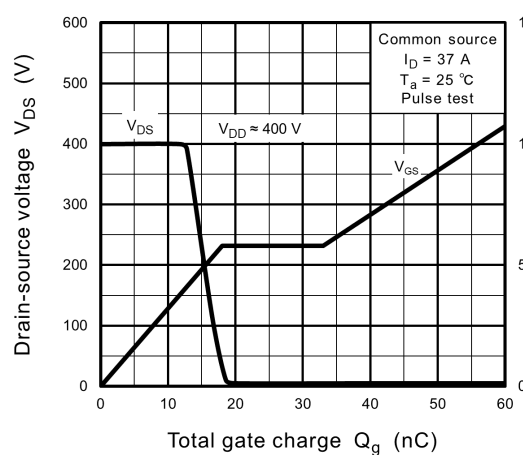


Fig. 8.11 Dynamic Input/Output Characteristics

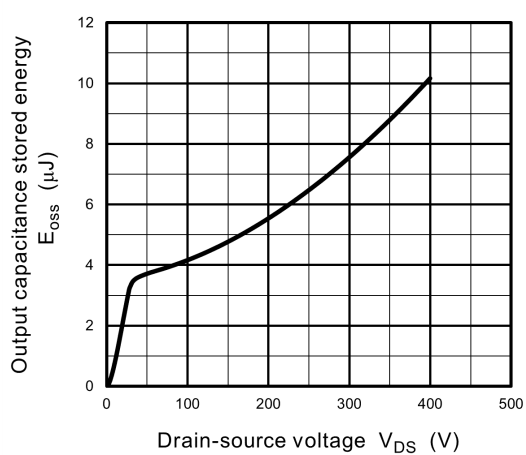


Fig. 8.12  $E_{oss} - V_{DS}$

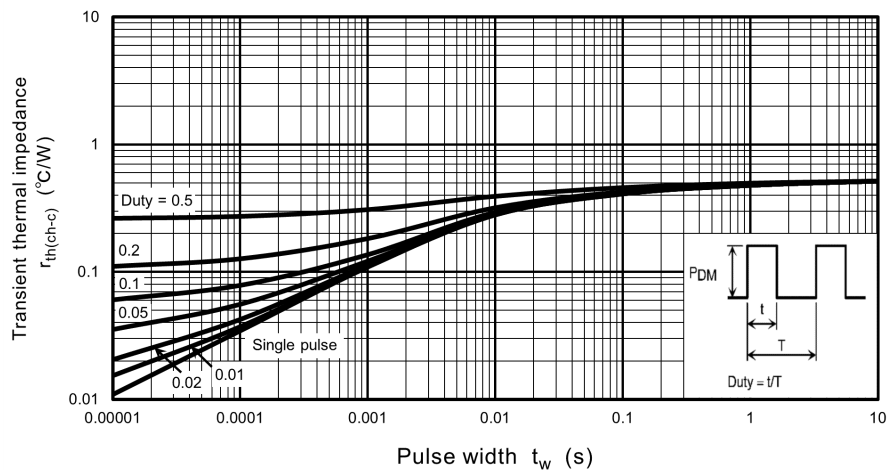


Fig. 8.13  $r_{th} - t_w$   
(Guaranteed Maximum)

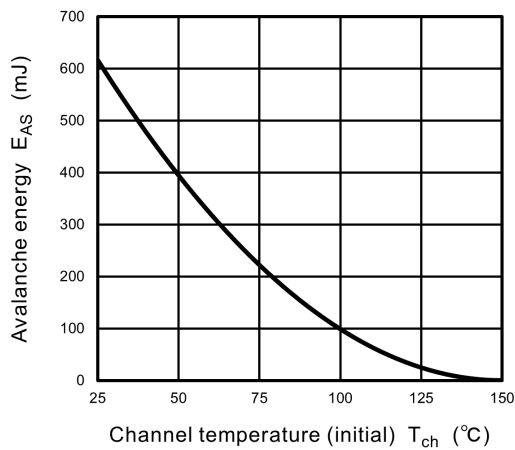


Fig. 8.14  $E_{AS} - T_{ch}$   
(Guaranteed Maximum)

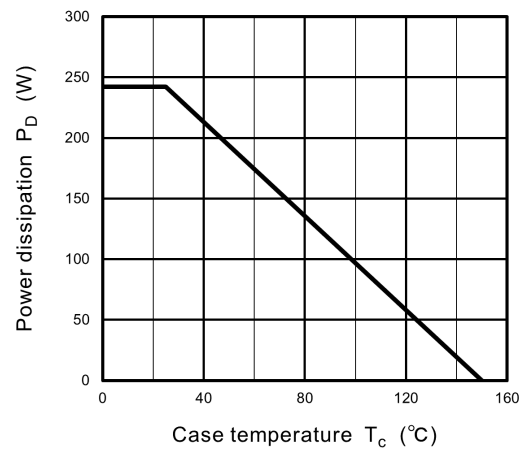


Fig. 8.15  $P_D - T_c$   
(Guaranteed Maximum)

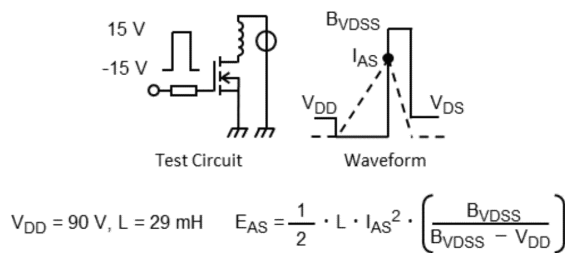


Fig. 8.16 Test Circuit/Waveform

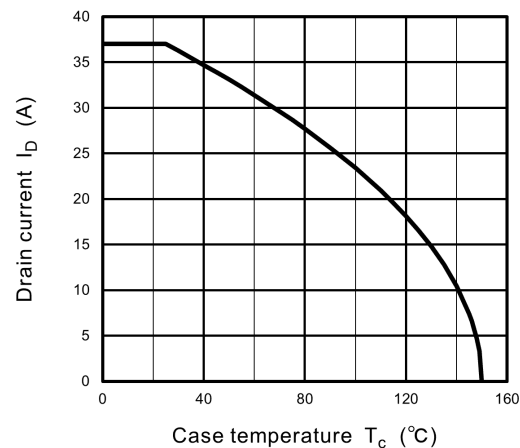
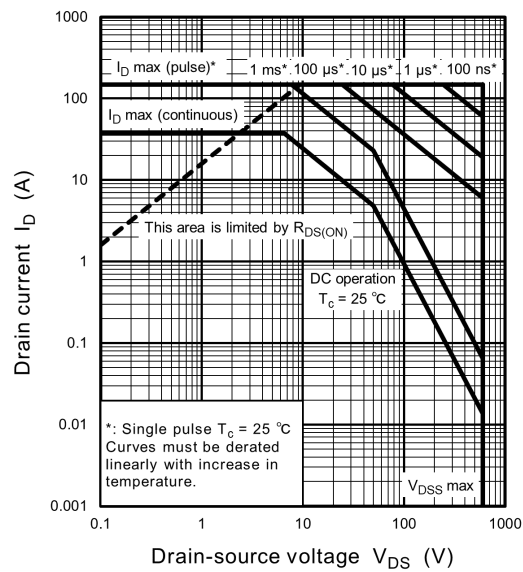


Fig. 8.17  $I_D - T_c$   
(Guaranteed Maximum)

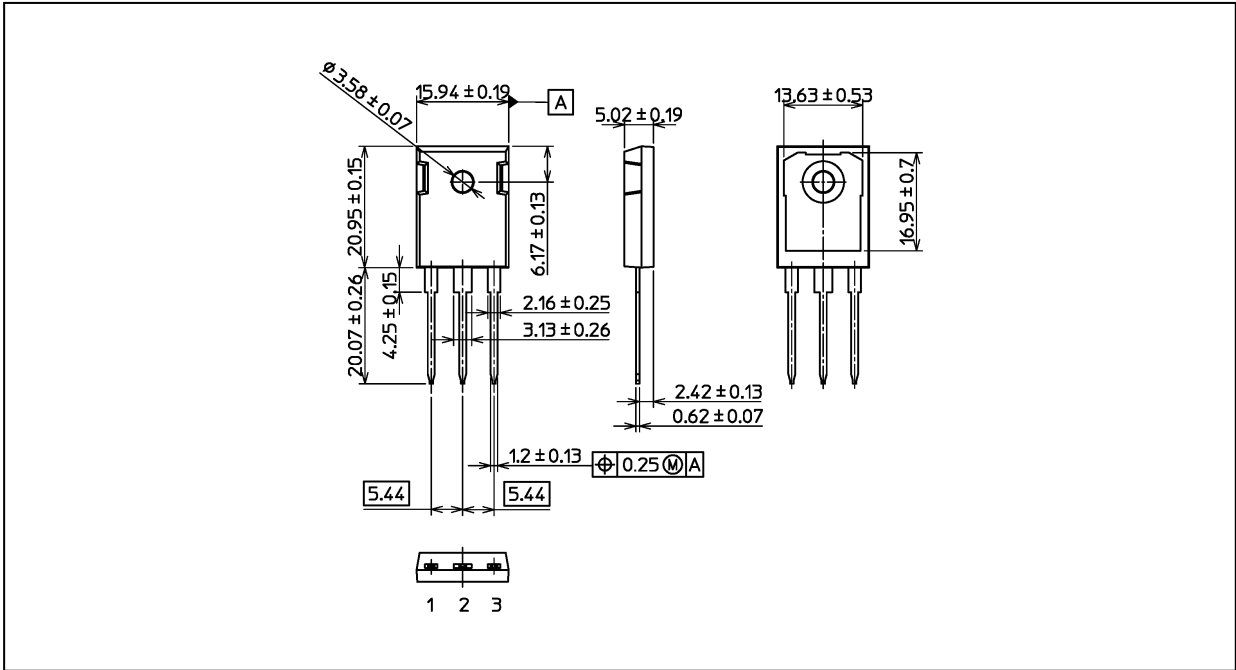


**Fig. 8.18 Safe Operating Area  
(Guaranteed Maximum)**

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 6.15 g (typ.)

Package Name(s)
TOSHIBA: 2-16L1A
Nickname: TO-247



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